

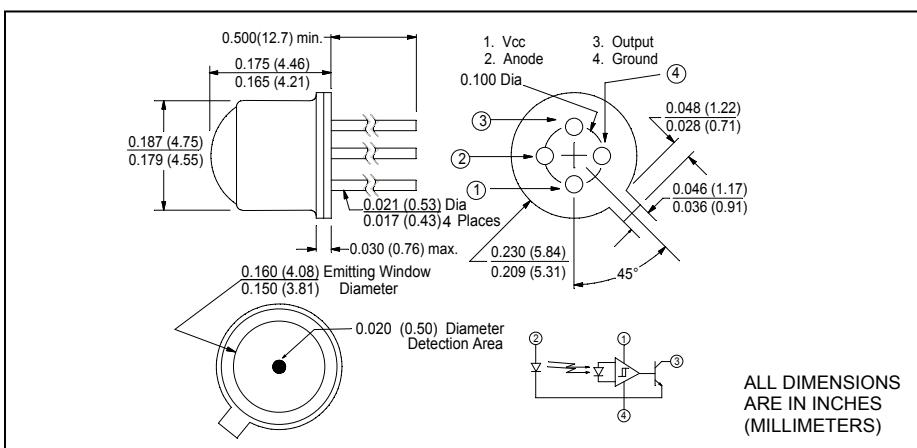
# CLI700

IRED – Photo-IC

Reflective Object Sensor



March, 2002



## features

- 0.020" dia. light pipe aperture
- TO-72 package
- NPN buffer open collector output

## description

The CLI700 consists of an 880nm AlGaAs IRED and an NPN, buffer, open collector photo-IC mounted on a custom TO-72 header. The IRED emits a broad radiation pattern through the formed clear epoxy lens. Radiation reflected from the target is received by a 0.020" diameter fiber optic light pipe attached to the active area of the photo-IC.

## absolute maximum ratings ( $T_A = 25^\circ\text{C}$ unless otherwise stated)

|                                  |                 |
|----------------------------------|-----------------|
| storage temperature .....        | -40°C to +125°C |
| operating temperature .....      | -40°C to +100°C |
| lead soldering temperature ..... | 260°C           |

## IRED

|  |       |
|--|-------|
| continuous forward DC current .....    | 35mA  |
| reverse DC voltage .....               | 5V    |
| power dissipation <sup>(1)</sup> ..... | 100mW |

## PHOTO-IC

|                           |      |
|---------------------------|------|
| supply voltage.....       | 15V  |
| output sink current ..... | 25mA |

## note:

1. Derate linearly 1.33mW/°C from 25°C free air temperature to  $T_A = +100^\circ\text{C}$ .

**definition:** Output is buffer, open collector. Output is HIGH (OFF) when reflected light is sensed and LOW (ON) when reflected light is not sensed.

## electrical characteristics ( $T_A = 25^\circ\text{C}$ and $V_{CC} = 5.0\text{V}$ unless otherwise noted)

| symbol          | parameter                               | min  | typ  | max  | units         | test conditions                    |
|-----------------|---|------|------|------|---------------|------------------------------------|
| $V_F$           | IRED forward voltage                    | 1.40 | 1.50 | 1.65 | V             | $I_F = 20\text{mA}$                |
| $I_R$           | IRED reverse current                    | -    | -    | 10   | $\mu\text{A}$ | $V_R = 5\text{V}$                  |
| $\lambda_P$     | Peak emission wavelength                | -    | 880  | -    | nm            | $I_F = 20\text{mA}$                |
| BW              | Spectral bandwidth at half power points | -    | 80   | -    | nm            | $I_F = 20\text{mA}$                |
| $I_{CC}$        | Sensor supply current                   | -    | 4.0  | 10.0 | mA            | $V_{CC}=15\text{V}$                |
| $V_{OL}$        | Low level output voltage                | -    | 0.3  | 0.5  | V             | $I_C = 15\text{mA}$                |
|                 |   | -    | 0.5  | 0.8  | V             | $I_C = 25\text{mA}$                |
| $I_{OH}$        | High level output current               | -    | -    | 1.0  | $\mu\text{A}$ | $I_F = 35\text{mA}^{(1)}$          |
| $I_{FT}$        | Turn-on threshold (IRED current)        | -    | -    | 7.0  | mA            | $d = 0.03 \text{ inches}^{(2)}$    |
| $I_F(+)/I_F(-)$ | Hysteresis                              | -    | 12   | -    | %             |                                    |
| $t_r, t_f$      | Output rise and fall time               | -    | 200  | 500  | ns            | $R_L=200\Omega$ , duty cycle = 50% |
| $t_p$           | Propagation delay                       | -    | -    | 80   | $\mu\text{s}$ | $R_L=200\Omega$ , duty cycle = 50% |

**notes:** 1. No reflective surface.

2. Measured using a Kodak 90% diffuse reflectance neutral white test card.

Clairex reserves the right to make changes at any time to improve design and to provide the best possible product.

Revised 10/29/02